NSN 5962-01-090-0165

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-090-0165

Body Length:

Between 0.735 inches and 0.830 inches

Body Width:

Between 0.270 inches and 0.291 inches

Body Height:

Between 0.140 inches and 0.180 inches

Operating Tempurature Range:

-65.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and monolithic and positive outputs and w/storage and programmable and programmed and bipolar and high speed and w/enable

Inclosure Material:

inclosure material.

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

10 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-1.5 volts power source and 5.5 volts power source

Time Rating Per Chacteristic:

90.00 nanoseconds propagation delay time, low to high level output and 90.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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